

International IR Rectifier

SERIES IRK.166, .196, .236

STANDARD RECOVERY DIODES

NEW INT-A-pak Power Modules

Features

- High Voltage
- Electrically Isolated by DBC Ceramic (Al₂O₃)
- 3500 V_{RMS} Isolating Voltage
- Industrial Standard Package
- High Surge Capability
- Glass Passivated Chips
- Modules uses High Voltage Power diodes in four Basic Configurations
- Simple Mounting
- UL E78996 approved 

165 A

195 A

230 A

Applications

- DC Motor Control and Drives
- Battery Charges
- Welders
- Power Converters

Major Ratings and Characteristics

Parameters	IRK.166..	IRK.196..	IRK.236..	Units
I _{F(AV)}	165	195	230	A
@ T _C	100	100	100	°C
I _{F(RMS)}	260	305	360	A
I _{FSM} @ 50Hz	4000	4750	5500	A
@ 60Hz	4200	4980	5765	A
I ² t @ 50Hz	80	113	151	KA ² s
@ 60Hz	73	103	138	KA ² s
I ² √t	798	1130	1516	KA ² √s
V _{RRM}	400 to 1600			V
T _J range	-40 to 150			°C

CASE STYLE NEW INT-A-PAK



Electrical Specifications

Voltage Ratings

Type number	Voltage Code	V_{RRM} , Maximum repetitive peak reverse voltage V	V_{RSM} , Maximum non-repetitive peak reverse voltage V	I_{RRM} 150°C mA
IRK.166	04	400	500	20
IRK.196	08	800	900	
IRK.236	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

www.DataSheet4U.com

Forward Conduction

Parameter	IRK.166	IRK.196	IRK.236	Units	Conditions
$I_{F(AV)}$ Max. average on-state current @ Case temperature	165	195	230	A	180° conduction, half sine wave
	100	100	100	°C	
$I_{F(RMS)}$ Max. RMS on-state current	260	305	360	A	
I_{FSM} Maximum peak, one-cycle on-state, non-repetitive surge current	4000	4750	5500	A	t = 10ms No voltage reappplied
	4200	4980	5765		t = 8.3ms
	3350	4000	4630		t = 10ms 100% V_{RRM}
	3500	4200	4850		t = 8.3ms reappplied
I^2t Maximum I^2t for fusing	80	113	151	KA ² s	t = 10ms No voltage reappplied
	73	103	138		t = 8.3ms
	56	80	107		t = 10ms 100% V_{RRM}
	52	73	98		t = 8.3ms reappplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	798	1130	1516	KA ² √s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.73	0.69	0.7	V	(16.7% × π × $I_{F(AV)}$) < I < π × $I_{F(AV)}$, @ T_J max.
$V_{F(TO)2}$ High level value of threshold voltage	0.88	0.78	0.83	V	(I > π × $I_{F(AV)}$), @ T_J max.
r_{t1} Low level value on-state slope resistance	1.5	1.3	1.2	mΩ	(16.7% × π × $I_{F(AV)}$) < I < π × $I_{F(AV)}$, @ T_J max.
r_{t2} High level value on-state slope resistance	1.26	1.2	1.07	mΩ	(I > π × $I_{F(AV)}$), @ T_J max.
V_{FM} Maximum forward voltage drop	1.43	1.38	1.46	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25^\circ\text{C}$, 180° conduction Av. power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$

Blocking

I_{RRM} Maximum peak reverse and off-state leakage current	20	mA	$T_J = 150^\circ\text{C}$
V_{INS} RMS isolation voltage	3500	V	50Hz, circuit to base, all terminals shorted, t = 1s

Thermal and Mechanical Specifications

Parameter	IRK.166	IRK.196	IRK.236	Units	Conditions
T _J Max. junction operating temperature range	-40 to 150			°C	
T _{stg} Max. storage temperature range	-40 to 150			°C	
R _{thJC} Max. thermal resistance, junction to case	0.2	0.16	0.14	K/W	DC operation, per junction
R _{thCS} Max. thermal resistance, case to heatsink	0.05			K/W	Mounting surface smooth, flat and greased Per module
T Mounting torque ± 10%	IAP to heatsink	4 to 6		Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.
	busbar to IAP	4 to 6			
wt Approximate weight	200 (7.1)			g (oz)	
Case Style	New Int-A-Pak				

ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T _J max.					Rectangular conduction @ T _J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.166	0.025	0.03	0.038	0.055	0.089	0.018	0.031	0.041	0.057	0.089	K/W
IRK.196	0.016	0.019	0.024	0.034	0.053	0.012	0.02	0.026	0.035	0.054	
IRK.236	0.009	0.010	0.014	0.018	0.025	0.008	0.012	0.015	0.019	0.025	

Ordering Information Table

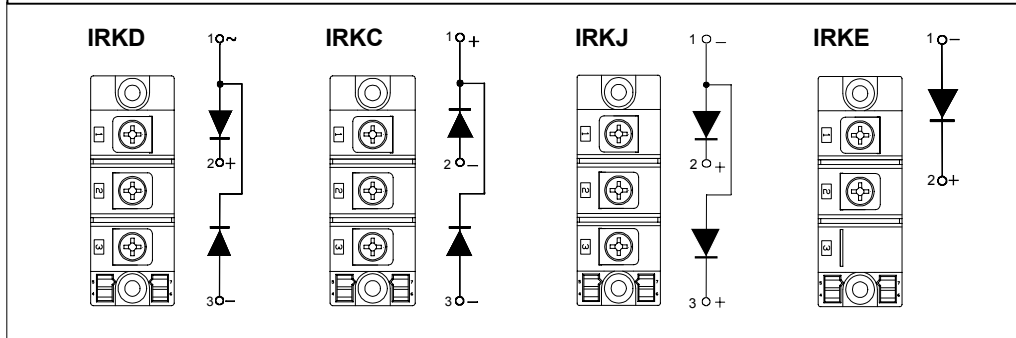
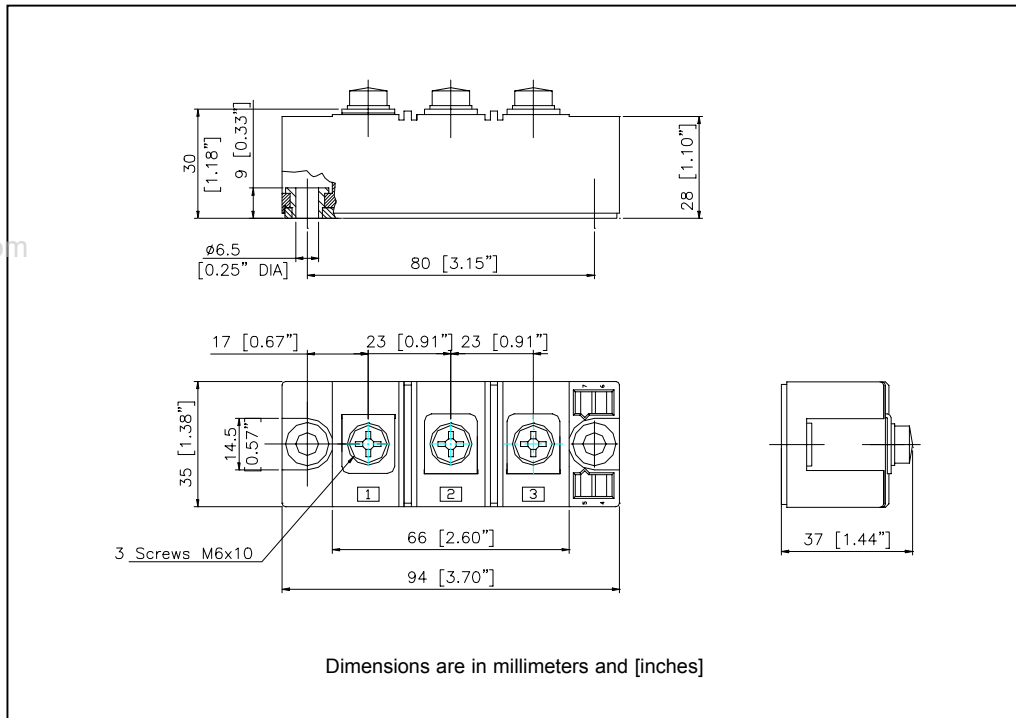
Device Code	IRK	D	236	/	16
	①	②	③		④
	1	2	3		4
	- Module Type	- Circuit Configuration	- Current Rating: I _{F(AV)}		- Voltage Code: Code x 100 = V _{RRM}

IRK.166, .196, .236 Series

Bulletin I27116 rev. C 03/02

International
IR Rectifier

Outline Table



NOTE: To order the Optional Hardware see Bulletin I27900

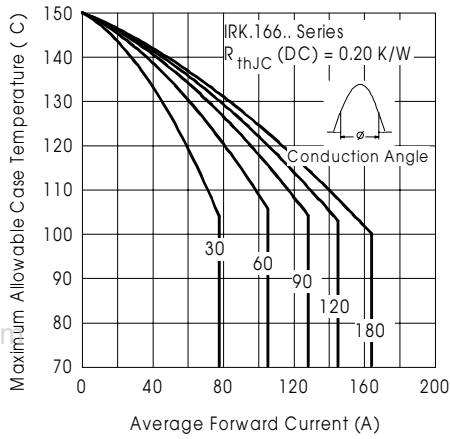


Fig. 1 - Current Ratings Characteristics

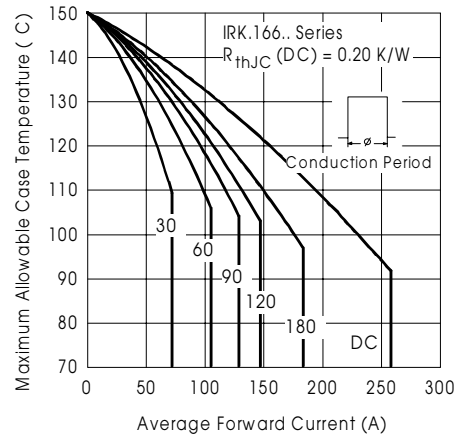


Fig. 2 - Current Ratings Characteristics

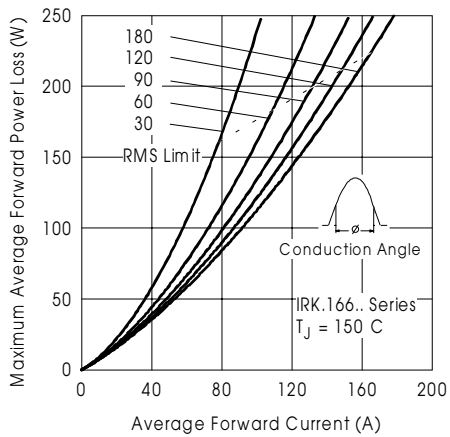


Fig. 3 - On-State Power Loss Characteristics

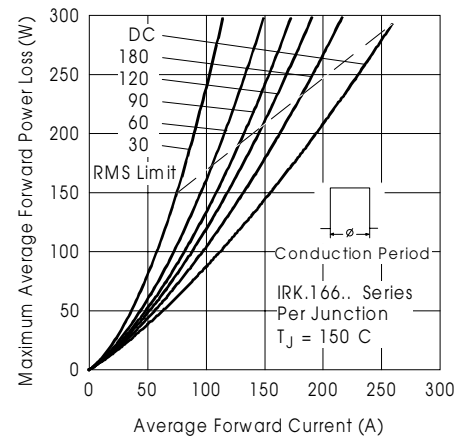


Fig. 4 - On-State Power Loss Characteristics

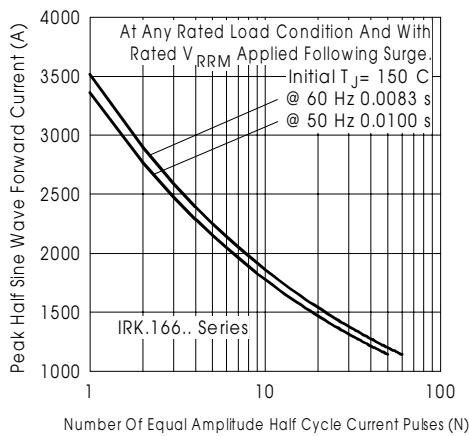


Fig. 5 - Maximum Non-Repetitive Surge Current

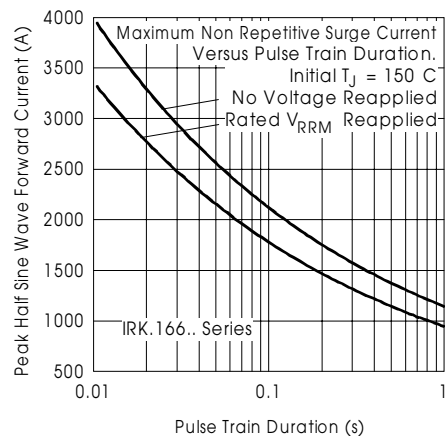


Fig. 6 - Maximum Non-Repetitive Surge Current

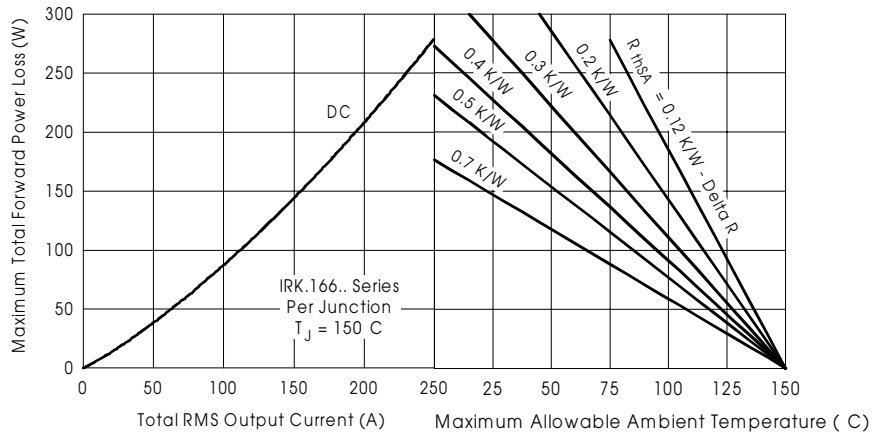


Fig.7 - On State Power Loss Characteristics

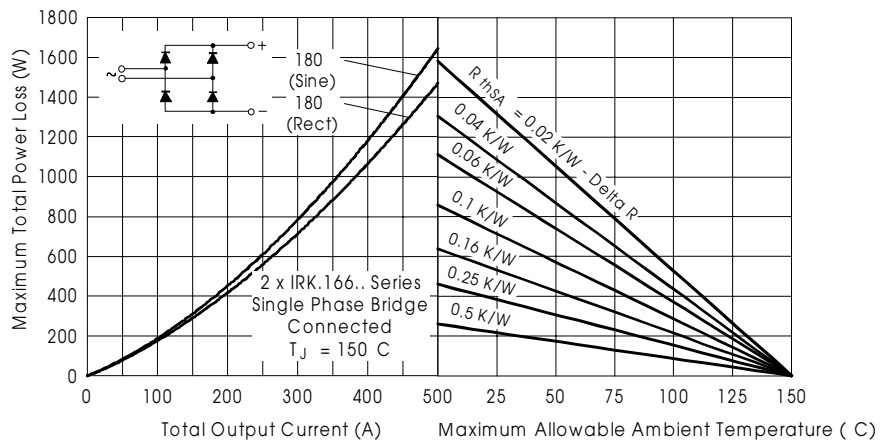


Fig.8 - On State Power Loss Characteristics

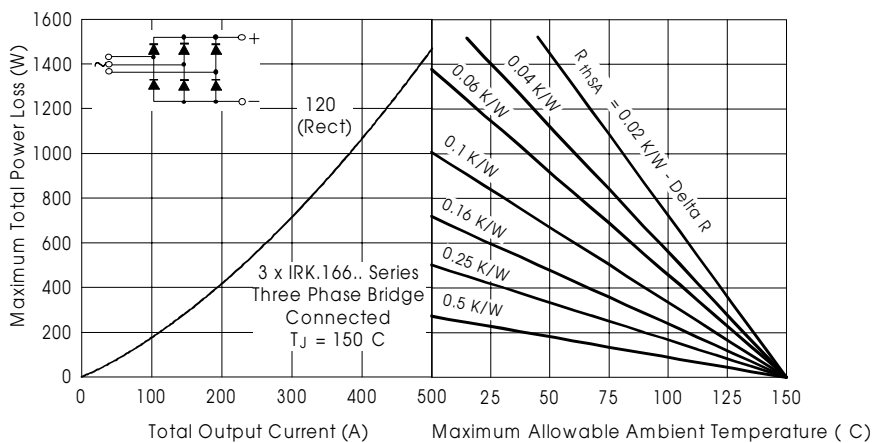


Fig.9 - On State Power Loss Characteristics

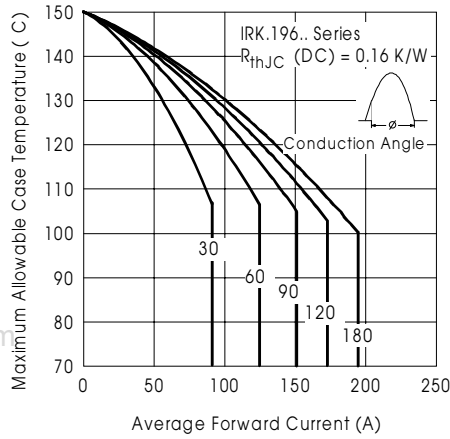


Fig. 10 - Current Ratings Characteristics

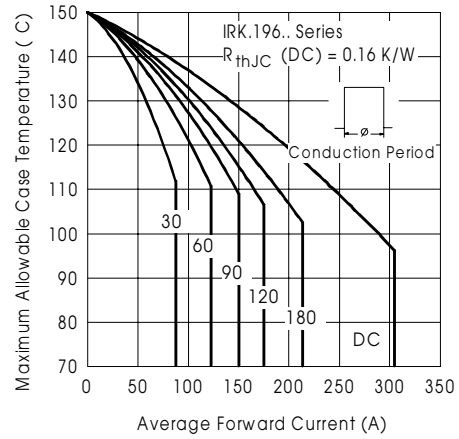


Fig. 11 - Current Ratings Characteristics

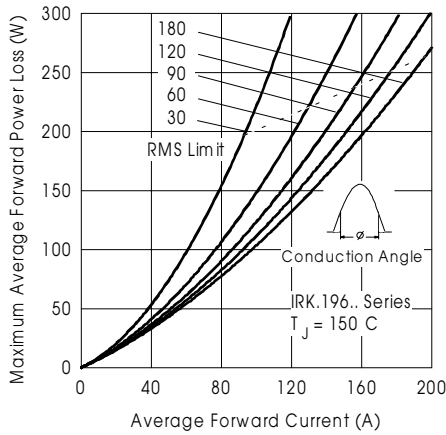


Fig. 12 - On-State Power Loss Characteristics

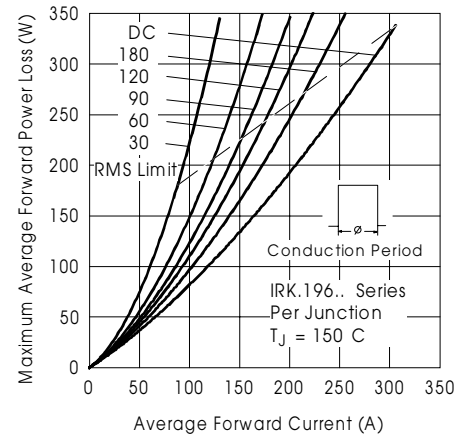


Fig. 13 - On-State Power Loss Characteristics

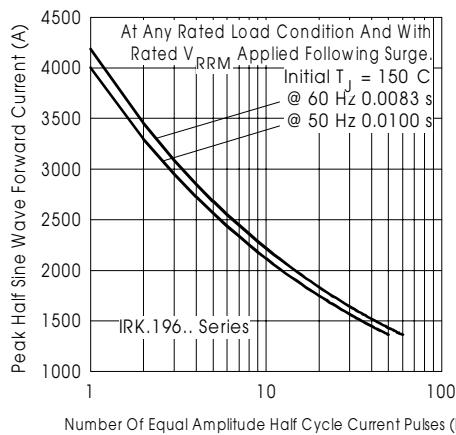


Fig. 14 - Maximum Non-Repetitive Surge Current

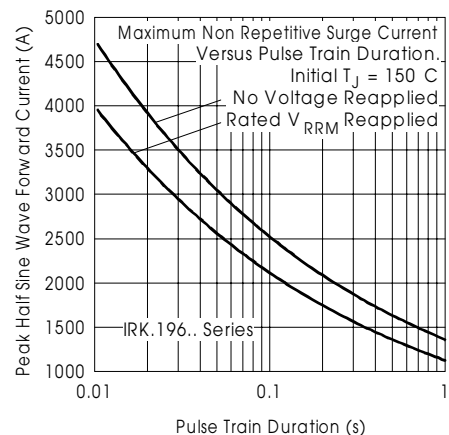


Fig. 15 - Maximum Non-Repetitive Surge Current

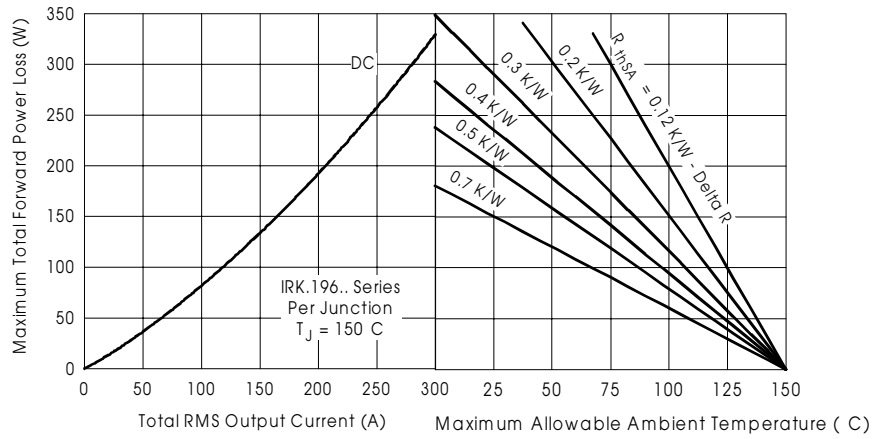


Fig.16 - On State Power Loss Characteristics

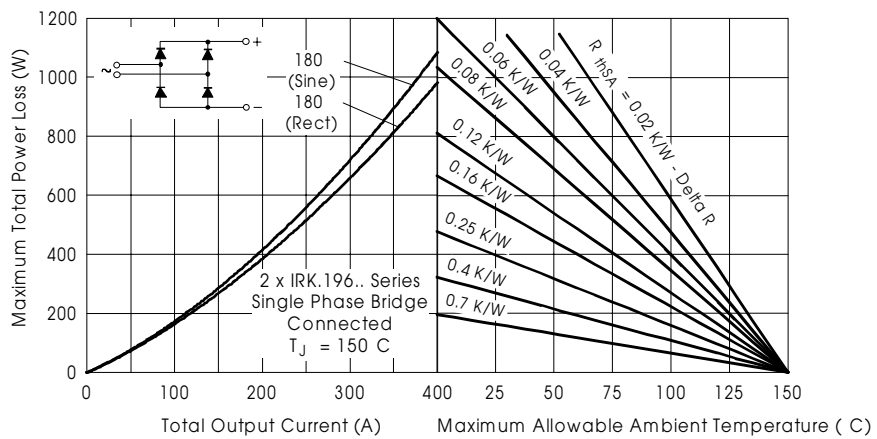


Fig.17 - On State Power Loss Characteristics

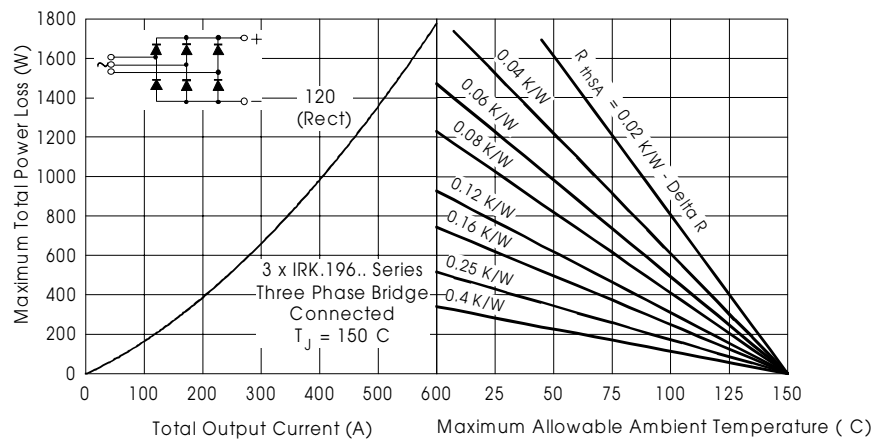


Fig.18- On State Power Loss Characteristics

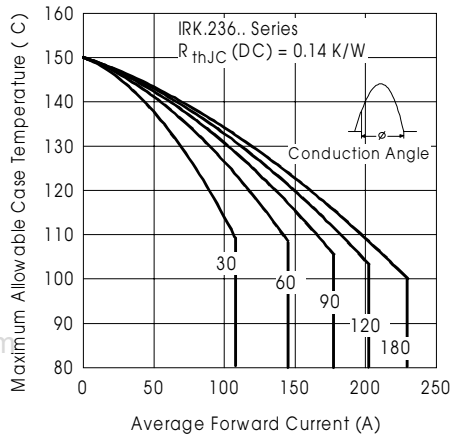


Fig. 19 - Current Ratings Characteristics

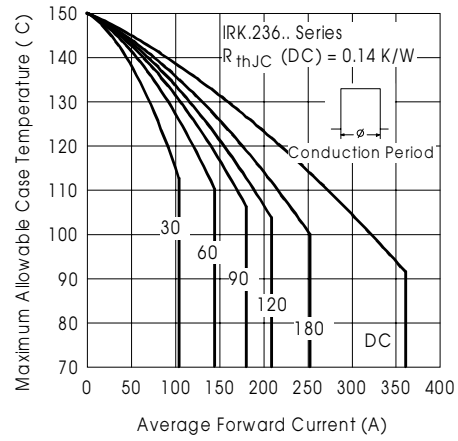


Fig. 20 - Current Ratings Characteristics

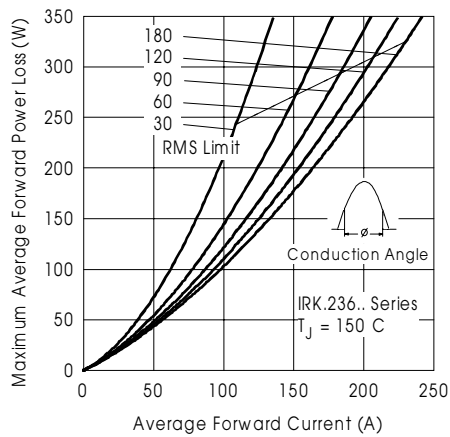


Fig. 21 - On-State Power Loss Characteristics

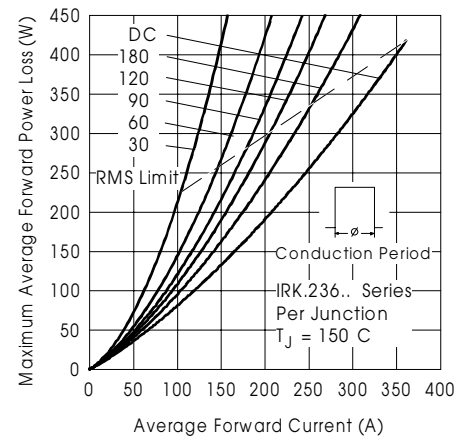


Fig. 22 - On-State Power Loss Characteristics

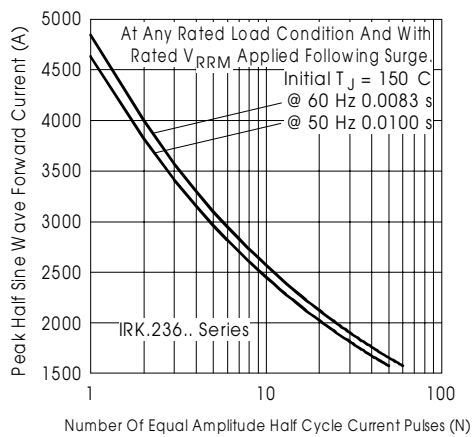


Fig.23 - Maximum Non-Repetitive Surge Current

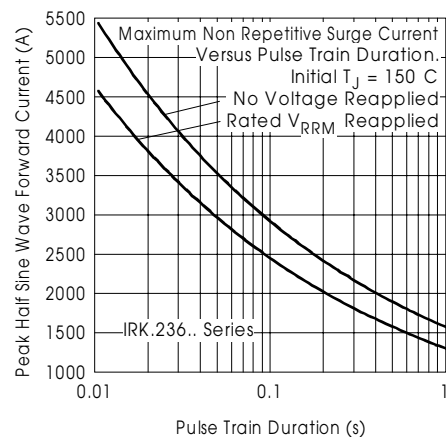


Fig. 24 - Maximum Non-Repetitive Surge Current

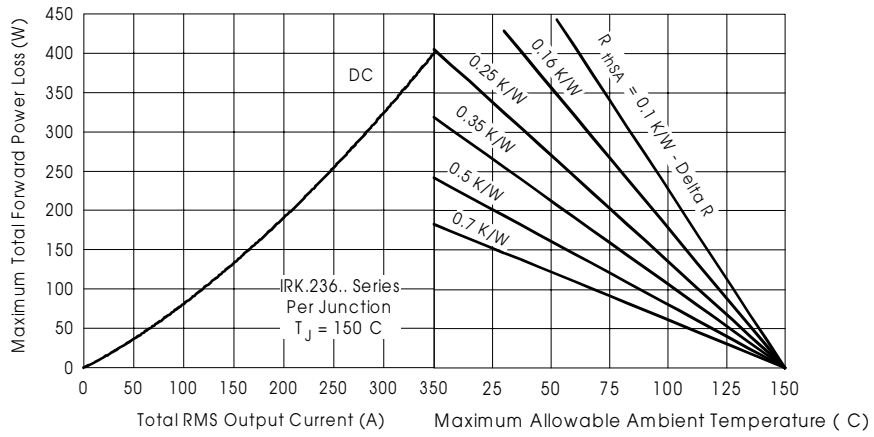


Fig.25 - On State Power Loss Characteristics

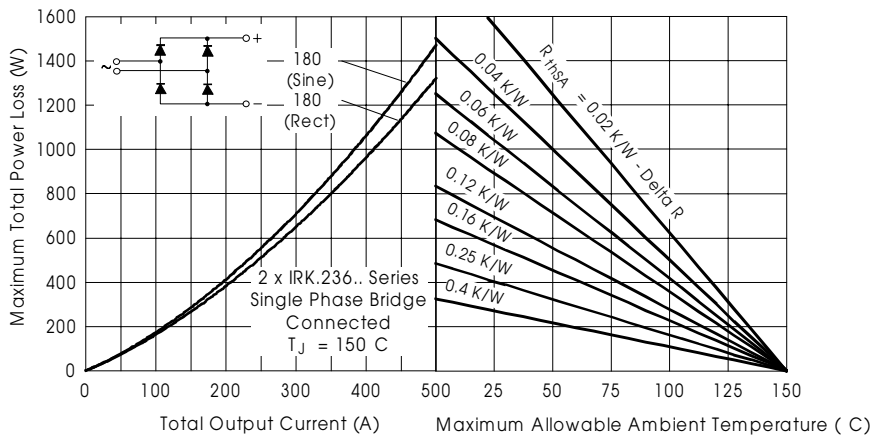


Fig.26 - On State Power Loss Characteristics

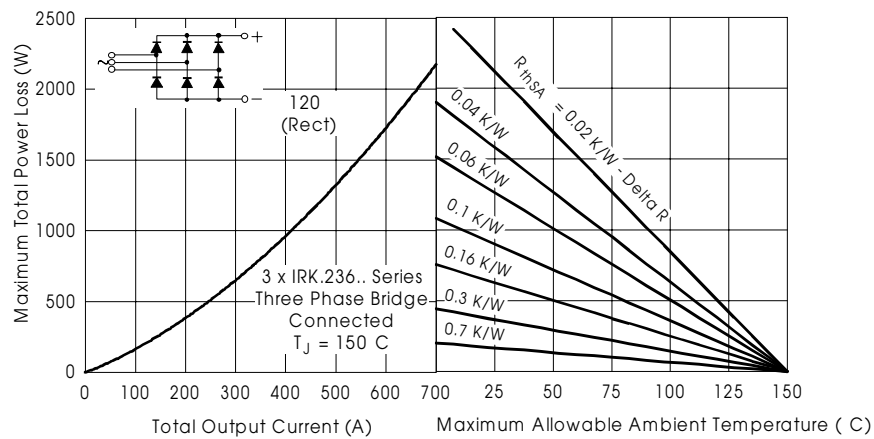


Fig.27 - On State Power Loss Characteristics

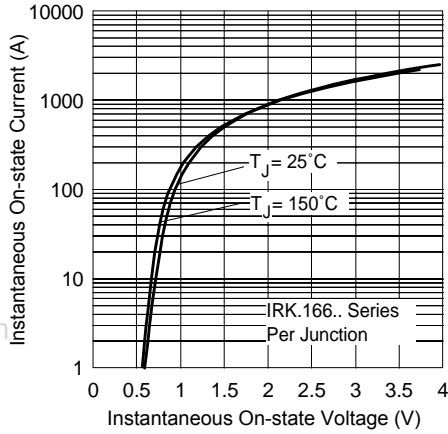


Fig.28 - On State Voltage Drop Characteristics

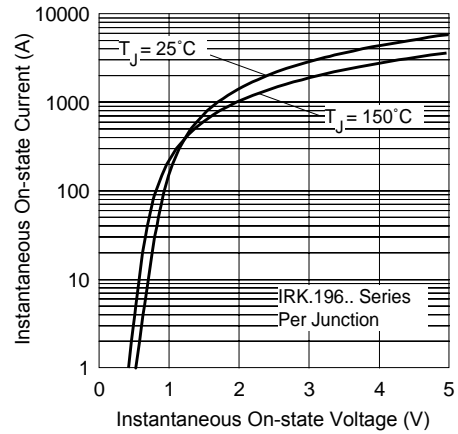


Fig.29 - On State Voltage Drop Characteristics

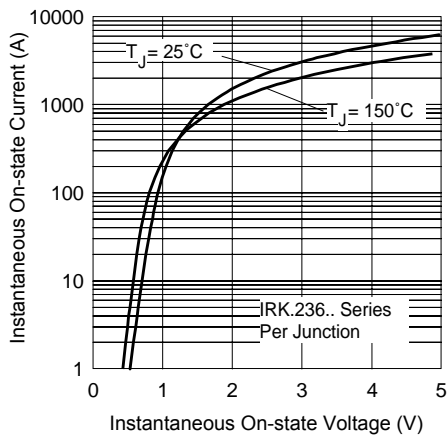


Fig.30 - On State Voltage Drop Characteristics

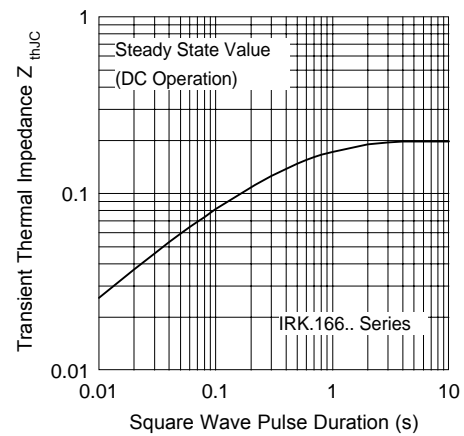


Fig.31 - Thermal Impedance Z_{thJC} Characteristics

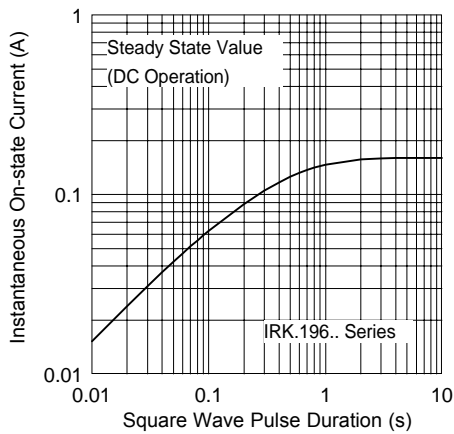


Fig.32 - Thermal Impedance Z_{thJC} Characteristics

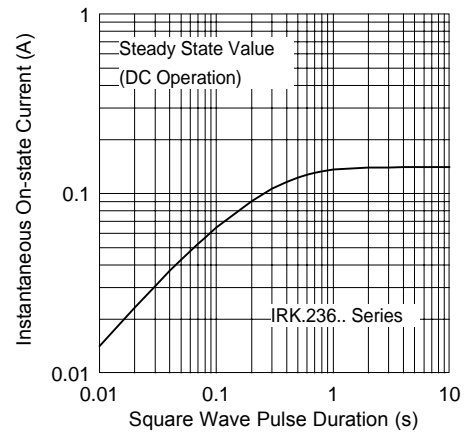


Fig.33 - Thermal Impedance Z_{thJC} Characteristics

IRK.166, .196, .236 Series

Bulletin I27116 rev. C 03/02

International
IOR Rectifier

www.DataSheet4U.com

Data and specifications subject to change without notice.
This product has been designed and qualified for Multiple Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/02